



May 2010

FDB8832_F085

N-Channel Logic Level PowerTrench® MOSFET

30V, 80A, 2.1mΩ

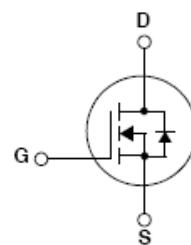
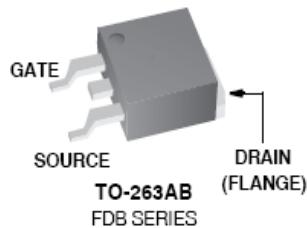
Features

- Typ $r_{DS(on)}$ = 1.5mΩ at V_{GS} = 5V, I_D = 80A
- Typ $Q_{g(5)}$ = 100nC at V_{GS} = 5V
- Low Miller Charge
- Low Q_{rr} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant



Applications

- 12V Automotive Load Control
- Starter / Alternator Systems
- Electronic Power Steering Systems
- ABS
- DC-DC Converters



Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Switching Characteristics						
$t_{(on)}$	Turn-On Time	$V_{DD} = 15\text{V}, I_D = 80\text{A}$ $V_{GS} = 5\text{V}, R_{GS} = 1.5\Omega$	-	-	155	ns
$t_{d(on)}$	Turn-On Delay Time		-	24	-	ns
t_r	Turn-On Rise Time		-	73	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	54	-	ns
t_f	Turn-Off Fall Time		-	38	-	ns
t_{off}	Turn-Off Time		-	-	149	ns

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Voltage	$I_{SD} = 75\text{A}$	-	0.8	1.25	V
		$I_{SD} = 40\text{A}$	-	0.8	1.0	V
t_{rr}	Reverse Recovery Time	$I_F = 75\text{A}, di/dt = 100\text{A}/\mu\text{s}$	-	59	77	ns
Q_{rr}	Reverse Recovery Charge	$I_F = 75\text{A}, di/dt = 100\text{A}/\mu\text{s}$	-	67	87	nC

Notes:1: Starting $T_J = 25^\circ\text{C}$, $L = 0.61\text{mH}$, $I_{AS} = 64\text{A}$, $V_{DD} = 30\text{V}$, $V_{GS} = 10\text{V}$.

2: Pulse width = 100s.

This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: <http://www.aecouncil.com/>
 All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

Typical Characteristics

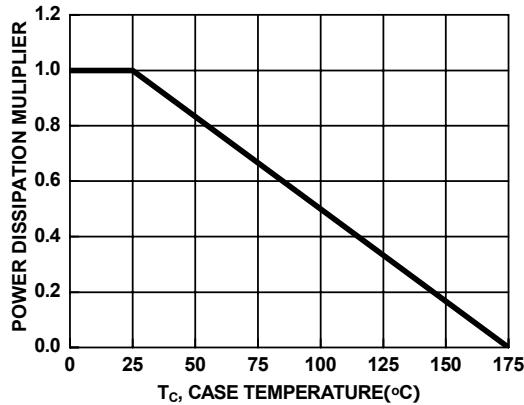


Figure 1. Normalized Power Dissipation vs Case Temperature

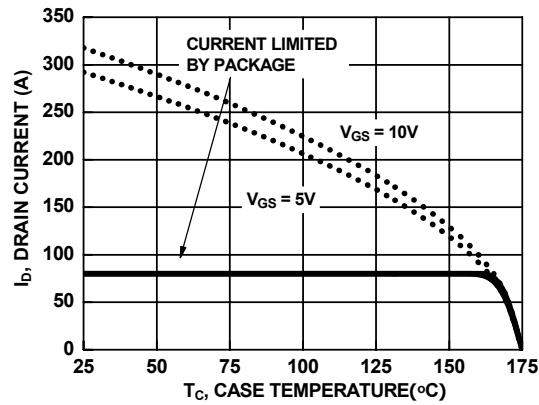


Figure 2. Maximum Continuous Drain Current vs Case Temperature

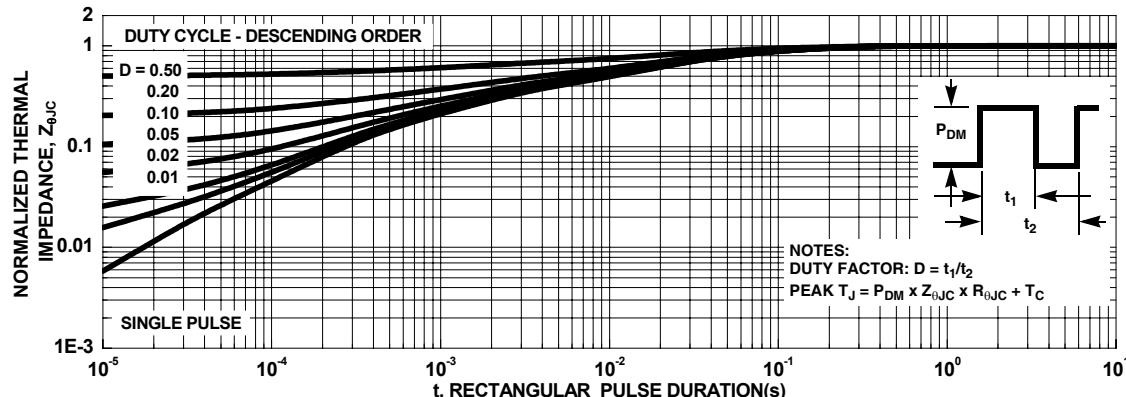


Figure 3. Normalized Maximum Transient Thermal Impedance

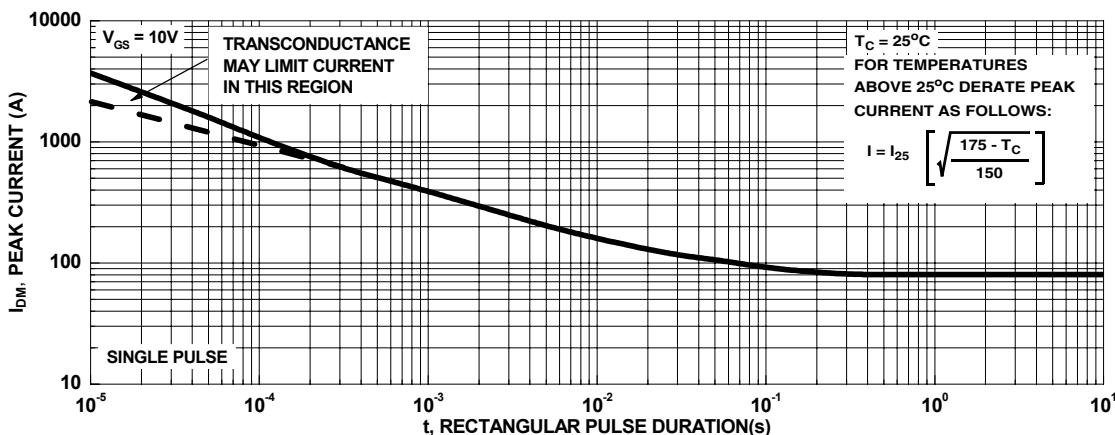


Figure 4. Peak Current Capability

Typical Characteristics

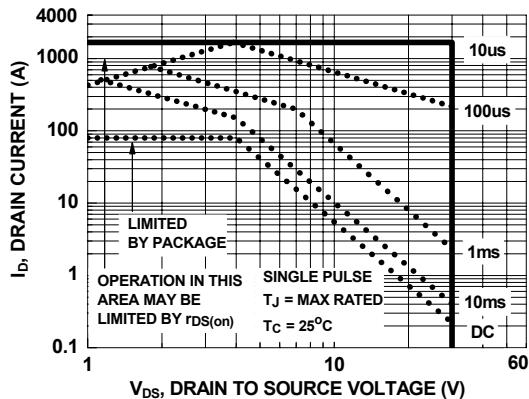
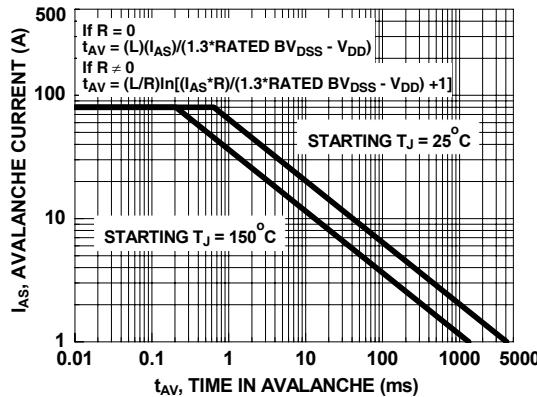


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching Capability

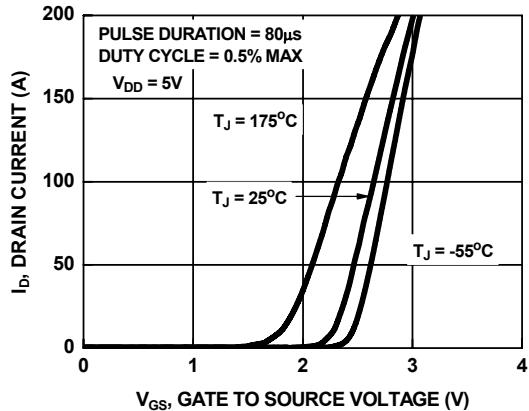


Figure 7. Transfer Characteristics

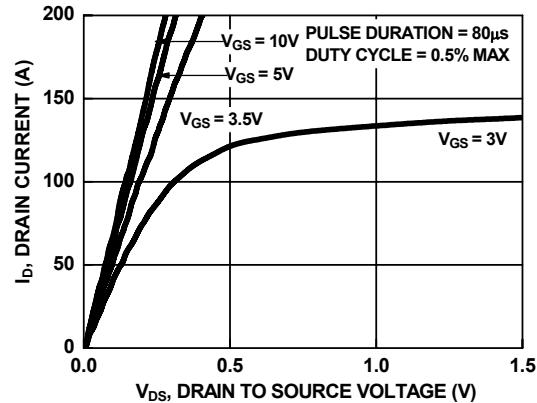


Figure 8. Saturation Characteristics

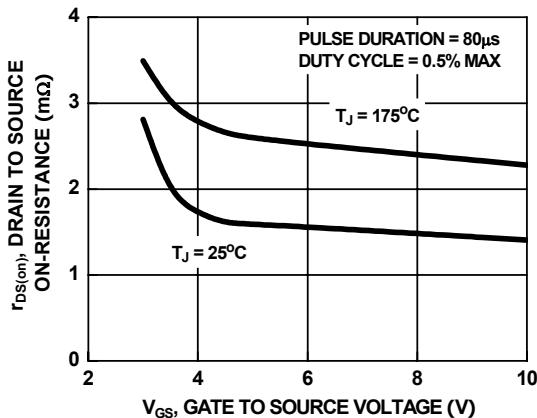


Figure 9. Drain to Source On-Resistance Variation vs Gate to Source Voltage

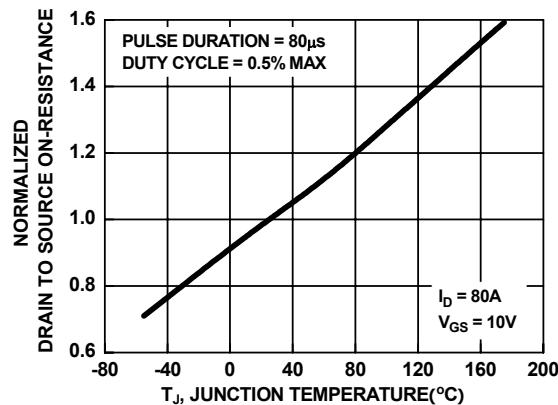


Figure 10. Normalized Drain to Source On Resistance vs Junction Temperature

Typical Characteristics

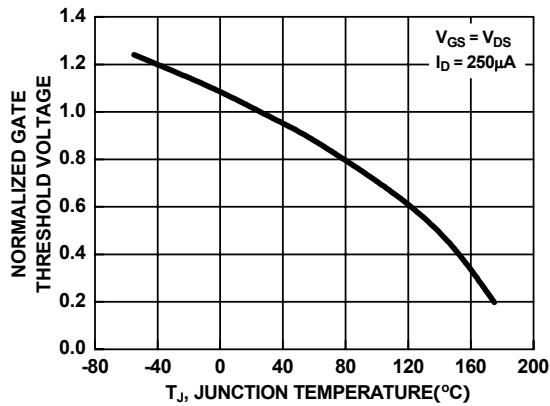


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

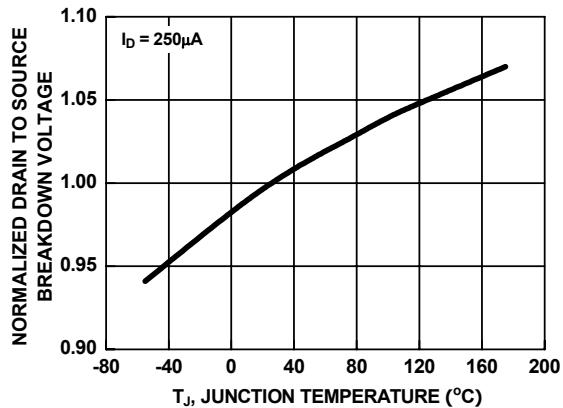


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

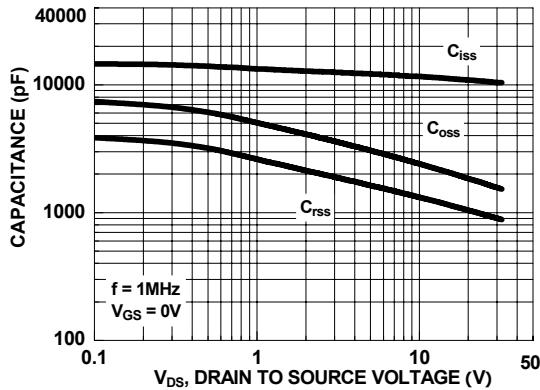


Figure 13. Capacitance vs Drain to Source Voltage

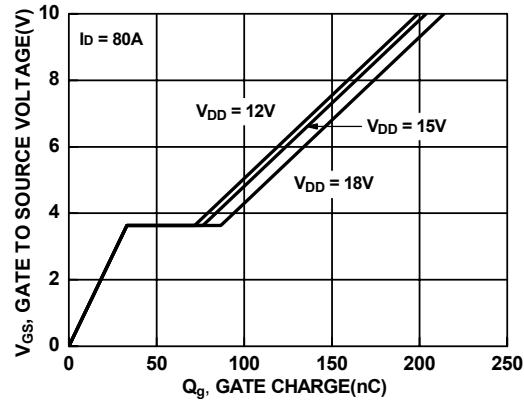


Figure 14. Gate Charge vs Gate to Source Voltage



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